

512k x 8 Low Power SRAM 32pin SOP Package

Revision	Details	Date
Rev 1.0	Preliminary datasheet	Mar. 2019

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FEATURES

- Fast access time : 70ns
- Low power consumption: Operating current : 20mA (TYP.) Standby current : 4µA (TYP.)
- Single 2.7V ~ 5.5V power supply
- All outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage : 1.5V (MIN.)
- ROHS Compliant-Pb free
- Package : 32-pin 450 mil SOP
- Operating Temperature Automotive Grade 1 -40°C ~+125°C

PRODUCT FAMILY

GENERAL DESCRIPTION

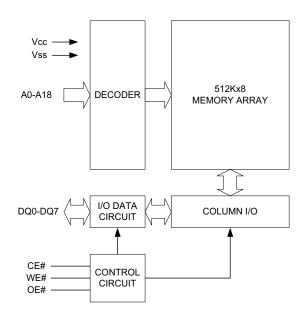
The AS6C4008-70SAN is a 4,194,304-bit low power CMOS static random access memory organized as 524,288 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

The AS6C4008-70SAN is well designed for very low power system applications, and particularly well suited for battery back-up nonvolatile memory application.

The AS6C4008-70SAN operates from a single power supply of 2.7V \sim 5.5V and all inputs and outputs are fully TTL compatible

Product	Operating	Vec Pango	Speed	Power D	Dissipation
Family	Temperature	Vcc Range	Speed	Standby(IsB1TYP.)	Operating(Icc,TYP.)
AS6C4008-70SAN	-40℃ ~+125℃	2.7 ~ 5.5V	70ns	4µA	20mA

FUNCTIONAL BLOCK DIAGRAM

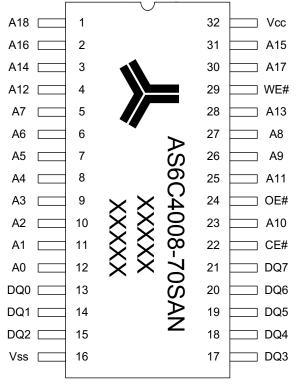


PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A18	Address Inputs
DQ0 – DQ7	Data Inputs/Outputs
CE#	Chip Enable Inputs
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground
NC	No Connection



PIN CONFIGURATION



SOP



ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Voltage on Vcc relative to Vss	Vt1	-0.5 to 6.5	V
Voltage on any other pin relative to Vss	Vt2	-0.5 to Vcc+0.5	V
Operating Temperature	TA	-40 to 125(A grade)	°C
Storage Temperature	Тѕтс	-65 to 150	°C
Power Dissipation	PD	1	W
DC Output Current	Ιουτ	50	mA

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	Н	Х	Х	High-Z	I _{SB1}
Output Disable	L	Н	Н	High-Z	lcc,lcc1
Read	L	L	Н	Dout	lcc,lcc1
Write	L	Х	L	Din	lcc,lcc1

Note: $H = V_{IH}$, $L = V_{IL}$, X = Don't care.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. *4	MAX.	UNIT
Supply Voltage	Vcc		2.7	3.0	5.5	V
Innut High Voltago	VIH ^{*1}	V _{CC} = 4.5V ~ 5.5V	2.4	-	Vcc+0.3	V
Input High Voltage	VIH	$V_{CC} = 2.7 V \sim 4.5 V$	2.2	-	Vcc+0.3	V
Input Low Voltage	VIL ^{*2}	V _{CC} = 4.5V ~ 5.5V	- 0.2	-	0.8	V
Input Low Voltage	VIL	$V_{CC} = 2.7 V \sim 4.5 V$	- 0.2	-	0.6	V
Input Leakage Current	Iц	$V_{CC} \ge V_{IN} \ge V_{SS}$	- 2	-	2	μA
Output Leakage Current	Ilo	Vcc ≧ Vou⊤ ≧ Vss, Output Disabled	- 2	-	2	μA
Output High Voltage	Vон	Iон = -1mA	2.4	2.7	-	V
Output Low Voltage	Vol	lo∟ = 2mA	-	-	0.4	V
Average Operating	lcc	Cycle time = Min. CE# = Vı∟ Iı/o = 0mA Other pins at Vı∟ or Vıн	-	20	50	mA
Power supply Current	lcc1	Cycle time = 1µs CE#≦0.2V, I⊮o = 0mA Other pins at 0.2V or Vcc-0.2V	-	4	10	mA
Standby Power Supply Current	Isb1	CE# ≧V _{CC} -0.2V Others at 0.2V or V _{CC} - 0.2V	-	4	80	μA

Notes:

1. VIH(max) = V_{CC} + 3.0V for pulse width less than 6ns.

2. VIL(min) = Vss - 3.0V for pulse width less than 6ns.

3. Over/Undershoot specifications are characterized, not 100% tested.

4. Typical values are included for reference only and are not guaranteed or tested.

Typical values are measured at Vcc = Vcc(TYP.) and TA = 25 $^\circ C$

5. This parameter is measured at Vcc = 3.0V



CAPACITANCE (TA = 25°C, f = 1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	CIN	-	6	pF
Input/Output Capacitance	Cı/o	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to Vcc - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	Сь = 30pF + 1TTL, Іон/Іоь = -2mA/4mA

AC ELECTRICAL CHARACTERISTICS

(1) READ CYCLE

PARAMETER	SYM.	AS6C4008-70SAN		UNIT
		MIN.	MAX.	
Read Cycle Time	t _{RC}	70	-	ns
Address Access Time	taa	-	70	ns
Chip Enable Access Time	tace	-	70	ns
Output Enable Access Time	toe	-	35	ns
Chip Enable to Output in Low-Z	tc∟z*	10	-	ns
Output Enable to Output in Low-Z	tolz*	5	-	ns
Chip Disable to Output in High-Z	tcнz*	-	25	ns
Output Disable to Output in High-Z	tонz*	-	25	ns
Output Hold from Address Change	tон	10	-	ns

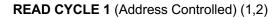
(2) WRITE CYCLE

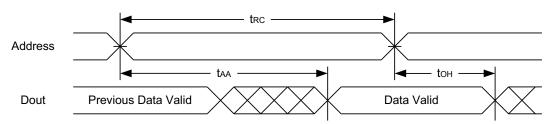
PARAMETER	SYM.	AS6C400	AS6C4008-70SAN	
		MIN.	MAX.	
Write Cycle Time	twc	70	-	ns
Address Valid to End of Write	taw	60	-	ns
Chip Enable to End of Write	tcw	60	-	ns
Address Set-up Time	tas	0	-	ns
Write Pulse Width	twp	55	-	ns
Write Recovery Time	twR	0	-	ns
Data to Write Time Overlap	tow	30	-	ns
Data Hold from End of Write Time	tdн	0	-	ns
Output Active from End of Write	tow*	5	-	ns
Write to Output in High-Z	twnz*	-	25	ns

*These parameters are guaranteed by device characterization, but not production tested.

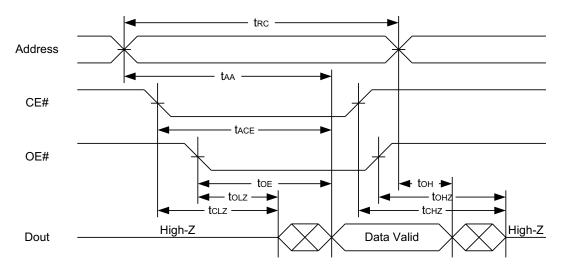


TIMING WAVEFORMS





READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)



Notes :

1.WE# is high for read cycle.

2.Device is continuously selected OE# = low, CE# = low.

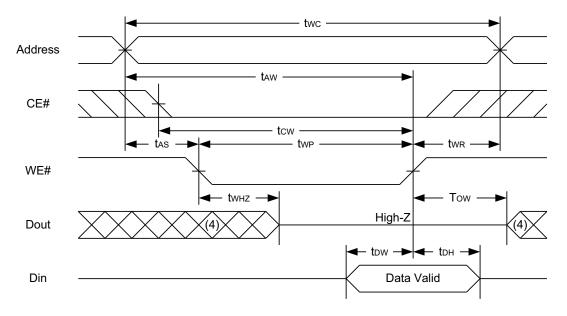
3.Address must be valid prior to or coincident with CE# = low,; otherwise tAA is the limiting parameter.

 $4.t_{CLZ}$, t_{OLZ} , t_{OLZ} , t_{OLZ} and t_{OHZ} are specified with C_L = 5pF. Transition is measured ±500mV from steady state.

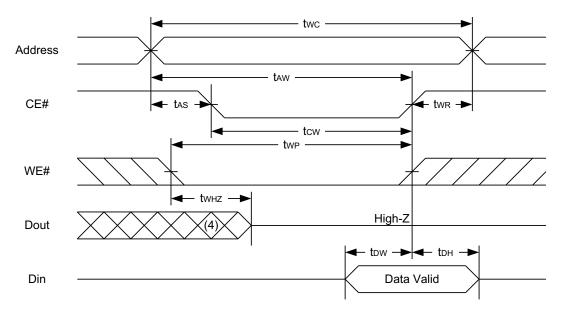
5.At any given temperature and voltage condition, t_{CHZ} is less than t_{CLZ} , t_{OHZ} is less than t_{OLZ} .



WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



WRITE CYCLE 2 (CE# Controlled) (1,2,5,6)



Notes :

1.WE#, CE# must be high during all address transitions.

2.A write occurs during the overlap of a low CE#, low WE#.

3.During a WE# controlled write cycle with OE# low, twp must be greater than twHz + tow to allow the drivers to turn off and data to be placed on the bus.

4. During this period, I/O pins are in the output state, and input signals must not be applied.

5. If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state. 6.tow and tw_{HZ} are specified with $C_L = 5pF$. Transition is measured ±500mV from steady state.

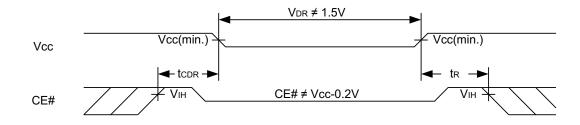


DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Vcc for Data Retention	Vdr	$CE# \ge V_{CC} - 0.2V$	1.5	-	5.5	V
Data Retention Current		V _{CC} = 1.5V CE# \ge V _{CC} - 0.2V Other pins at 0.2V or V _{CC} -0.2V	-	2	80	μA
Chip Disable to Data Retention Time	tcdr	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	tR		t RC*	-	-	ns

 $t_{\text{RC}^{\star}}$ = Read Cycle Time

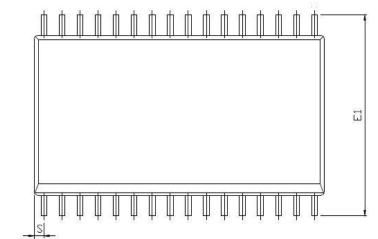
DATA RETENTION WAVEFORM

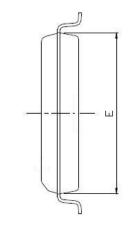




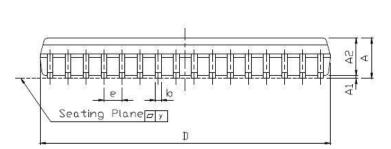
PACKAGE OUTLINE DIMENSION

32 pin 450 mil SOP Package Outline Dimension





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UNIT SYM.	INCH.(BASE)	MM(REF)
A	0.120(MAX)	3.048(MAX)
A1	0.004(MIN)	0.102(MIN)
A2	0.116(MAX)	2.946(MAX)
b	0.016(TYP)	0.406(TYP)
С	0.008(TYP)	0.203(TYP)
D	0.817(MAX)	20.75(MAX)
E	0.445±0.006	11.303±0.152
E1	0.555±0.025	14.097±0.635
е	0.050(TYP)	1.270(TYP)
L	0.033±0.017	0.838±0.432
L1	0.055±0.008	1.397±0.203
S	0.026(MAX)	0.660(MAX)
у	0.004(MAX)	0.101(MAX)
Θ	0° -10°	0° -10°



ORDERING INFORMATION

Package Type	Access Time	Temperature	Packing	Alliance Memory
	(Speed)(ns)	Range(℃)	Type	Part Number
32 Pin(450mil) SOP	70	-40℃~125℃	Tube Tape Reel	AS6C4008-70SAN AS6C4008-70SANTR

PART NUMBERING SYSTEM

AS6C	4008	-70	S	А	N
Low power SRAM prefix	Device Number 40 = 4M 08 = by 8	Access Time	Package Options: S = 32 pin 450 mil SOP	Temperature Range: A= Automotive (-40°C to +125°C)	N = Lead Free ROHS Compliant Part



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